Achieving the best system cost in Mid/High Power

Mid-Power LED – 3030 Series

STW9C2SA (Cool, Neutral, Warm)

RoHS

Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension. Package Size : 3.0x3.0x0.65mm

- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.

- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.

- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

- Thermally Enhanced Package Design
- Mid Power to High Power up to 1.4W
- Max. Driving Current 200mA
- Compact Package Size
- High Color Quality with CRI Min. 90
- CRI R9 > 50
- Pb-free Reflow Soldering Application

Key Applications

- Interior lighting
- General lighting
- Indoor & Outdoor displays
- Architectural / Decorative lighting

Table 1. Product Selection Table

Part Number	CCT			
	Color	Min.	Typ.	Max.
STW9C2SA	Cool White	4700K	5600K	7000K
STW9C2SA	Neutral White	3700K	4200K	4700K
STW9C2SA	Warm White	2600K	3000K	3700K

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Performance Characteristics

Table 2. Product Selection Guide, I_F = 100mA , T_a = 25⁰C, RH30%

Part Number	CCT (K) [1]	RANK	Luminous Intensity [2] I_V (cd)		Luminous Flux [3] Φ_V (lm)		CRI R_a
	Typ.		Min	Max	Min	Max	Min.
STW9C2SA	6500	J19	19.5	21.5	60.5	66.7	90
		K21	21.5	24	66.7	74.4	90
	5600	J19	19.5	21.5	60.5	66.7	90
		K21	21.5	24	66.7	74.4	90
		K24	24	26	74.4	80.6	90
	5000	J19	19.5	21.5	60.5	66.7	90
		K21	21.5	24	66.7	74.4	90
		K24	24	26	74.4	80.6	90
	4500	J19	19.5	21.5	59.7	65.8	90
		K21	21.5	24	65.8	73.4	90
		K24	24	26	73.4	79.6	90
	4000	J17	17	19.5	51.0	58.5	90
		J19	19.5	21.5	58.5	64.5	90
		K21	21.5	24	64.5	72.0	90
	3500	J17	17	19.5	51.0	58.5	90
		J19	19.5	21.5	58.5	64.5	90
		K21	21.5	24	64.5	72.0	90
	3000	J17	17	19.5	51.0	58.5	90
		J19	19.5	21	58.5	63.0	90
		K21	21	24	63.0	72.0	90
	2700	J17	17	19.5	51.0	58.5	90
		J19	19.5	21	58.5	63.0	90
		K21	21	24	63.0	72.0	90

Notes :

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

(2) Seoul Semiconductor maintains a tolerance of ±7% on Intensity and power measurements.

The luminous intensity Iv was measured at the peak of the spatial pattern which may not be

aligned with the mechanical axis of the LED package.

(3) The lumen table is only for reference.

Performance Characteristics

Table 3. Characteristics, I_F = 100mA , T_a = 25⁰C, RH30%

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Forward Current	I_F	-	100	200	mA
Forward Voltage[1]	V_F (100mA)	5.6	6.1	6.6	V
Reverse Voltage	V_R(5mA)	-	0.9	1.4	V
Luminous Intensity (5,000 K) [1]	I_v (100mA)	-	22 (68.2)	-	cd (lm)
	I_v (150mA)	-	31 (96.1)	-	
Luminous Intensity (3,500 K) [1]	I_v (100mA)	-	20 (60)	-	
	I_v (150mA)	-	28 (84)	-	
Color Rendering Index [1]	R_a	90	93	100	-
Viewing Angle [2]	$2\Theta_{1/2}$		120		
Power Dissipation	P_d	-	-	1.44	W
Junction Temperature	T_j	-	-	125	⁰C
Operating Temperature	T_{opr}	- 40	-	+ 85	⁰C
Storage Temperature	T_{stg}	- 40	-	+ 100	⁰C
Thermal resistance (J to S) [[3]	$R\theta_{J-S}$	-	10	-	℃/W
ESD Sensitivity(HBM) [4]	-	-	-	5000	V

Notes :

(1) Tolerance : VF :±0.2V, IV :±7%, Ra :±2, x,y :±0.007

(2) $2\Theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity

(3) Thermal resistance : Rth_{JS} (Junction / solder)

(4) A zener diode is included for ESD Protection.

- LED's properties might be different from suggested values like above and below tables if operation condition will be exceeded our parameter range. Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product.
- All measurements were made under the standardized environment of Seoul Semiconductor.

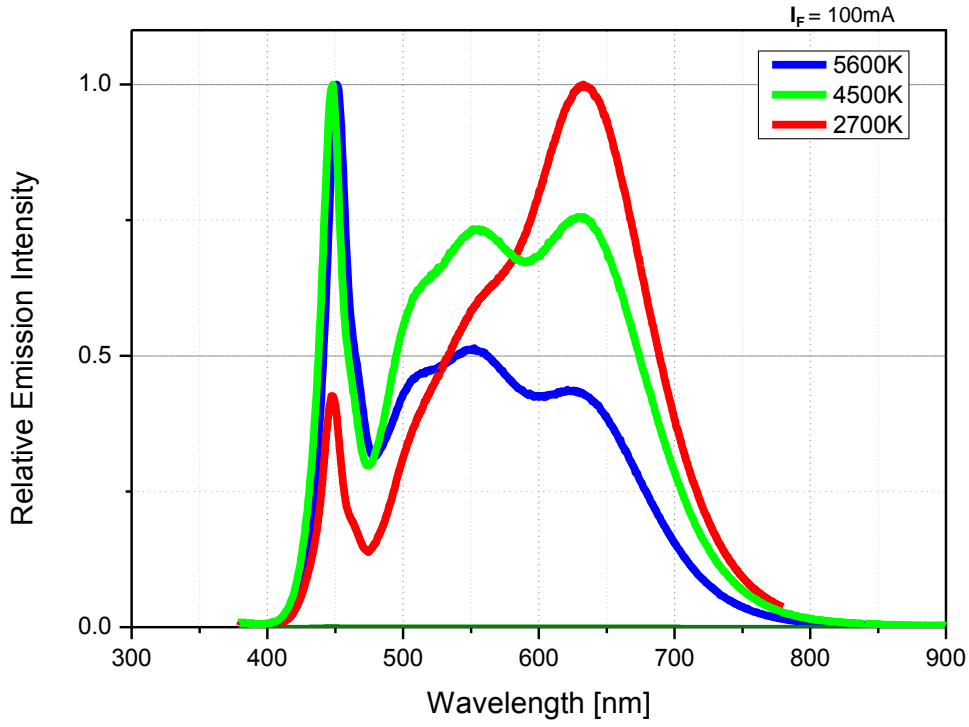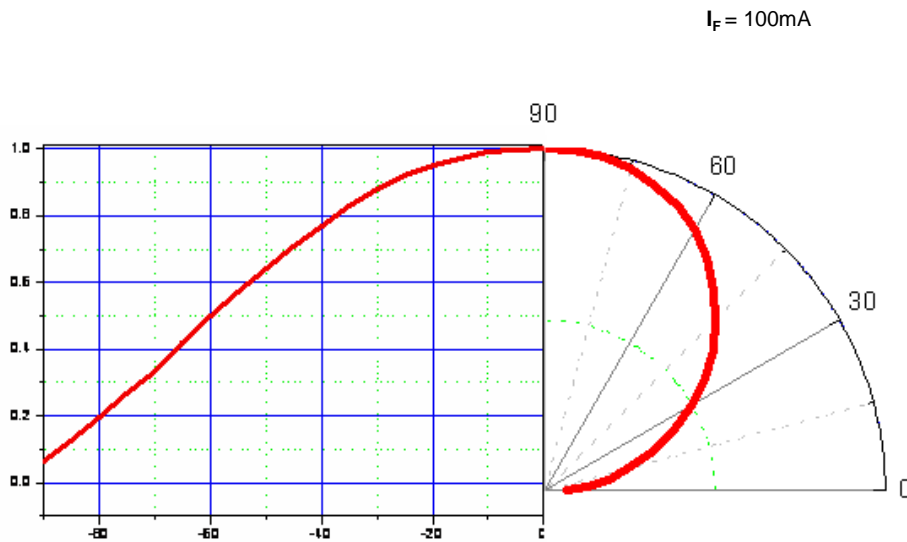# Characteristics Graph

Fig 1. Color Spectrum, T$_a$ = 25℃, RH30%

Fig 2. Viewing Angle Distribution

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Characteristics Graph

Fig 3. Forward Voltage vs. Forward Current , T_a = 25℃

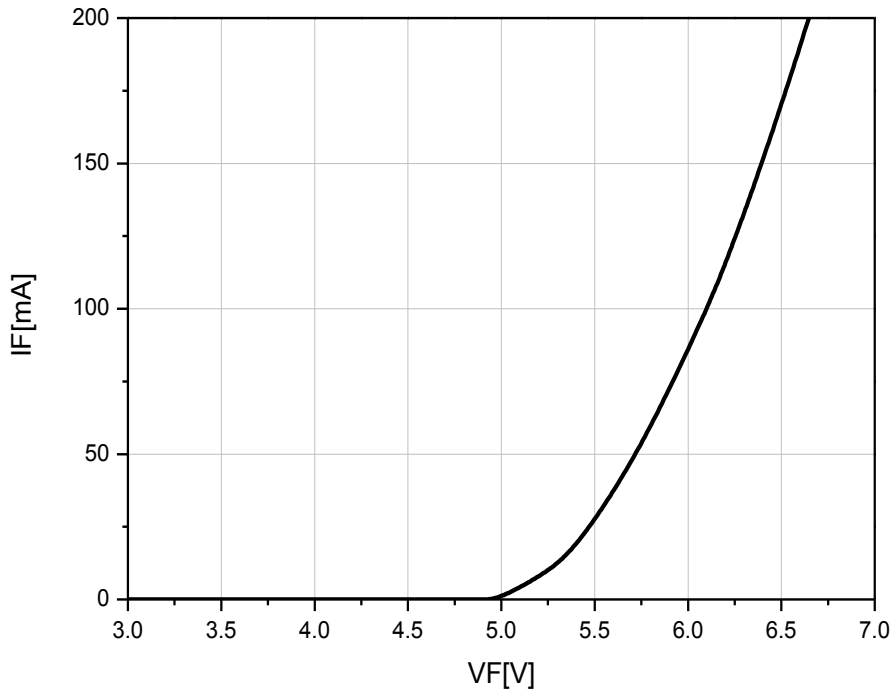**Fig 4. Forward Current vs. Relative Luminous Flux, T_a = 25℃**
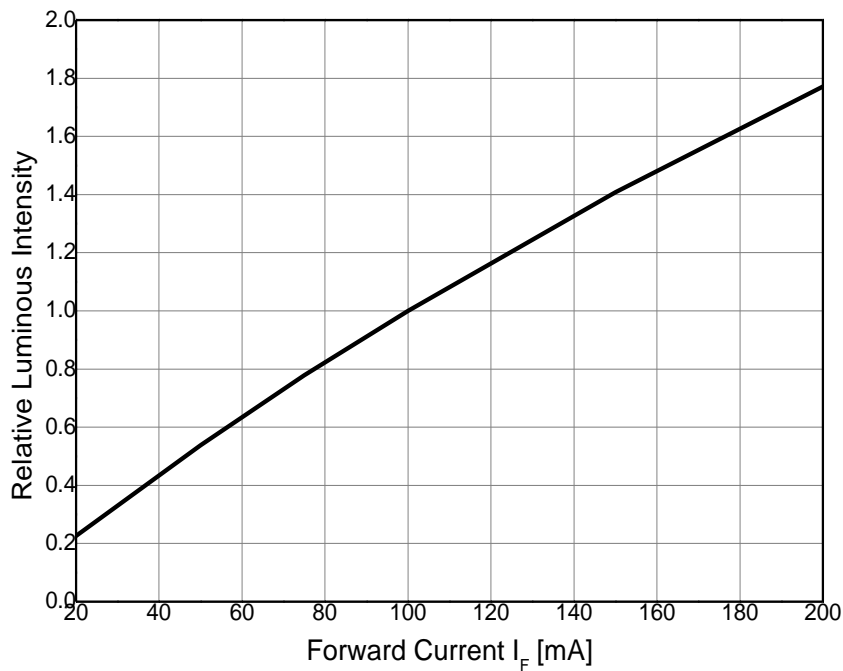
Characteristics Graph

Fig 5. Forward Current vs. CIE X, Y Shift , T_a = 25℃

(4200~7000K)

(2600~4200K)
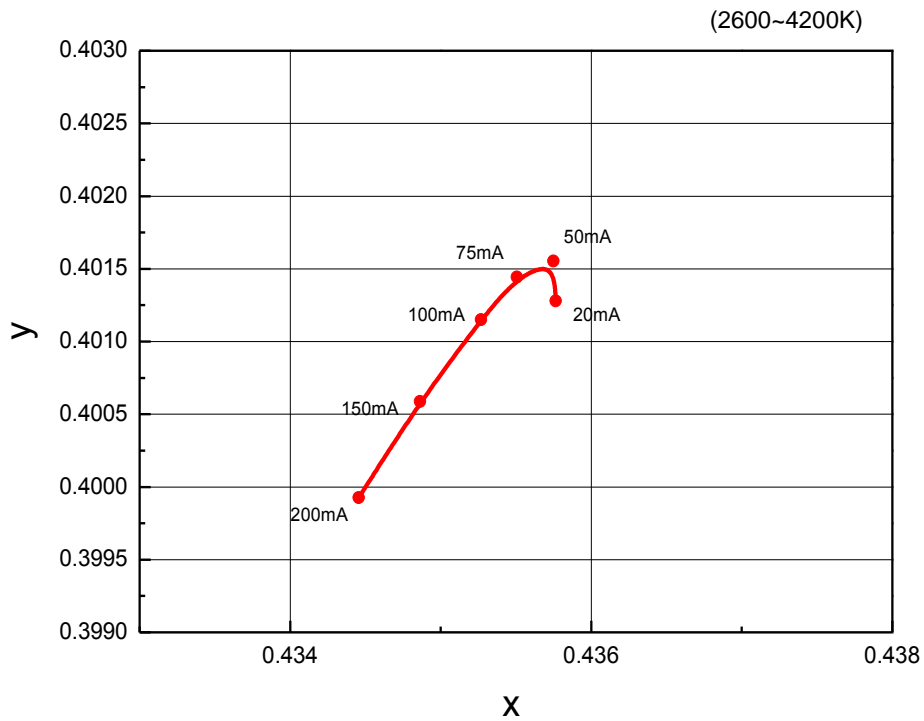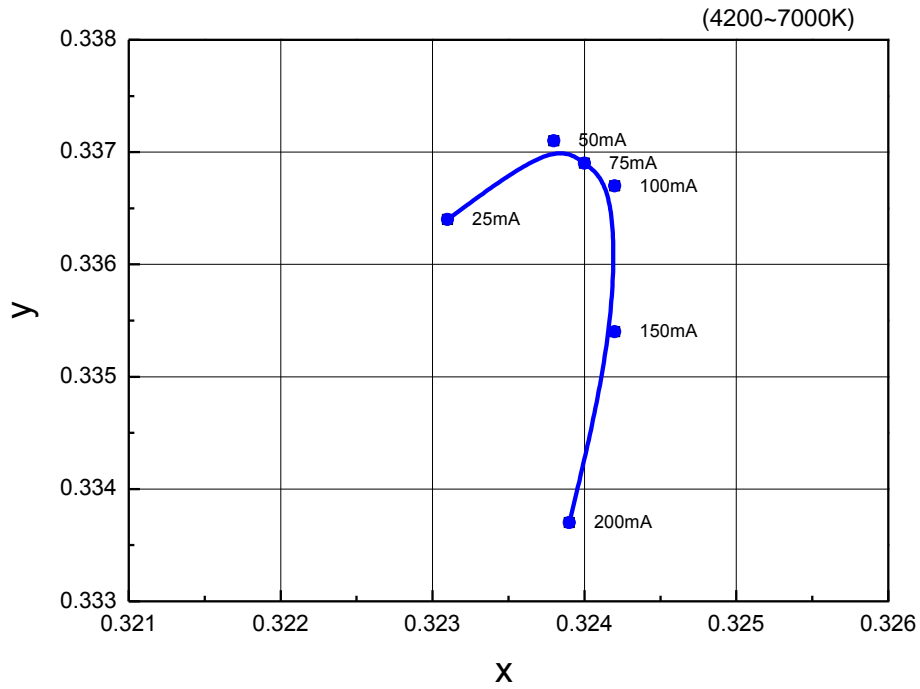
Characteristics Graph

Fig 6. Relative Light Output vs. Junction Temperature

I_F = 100mA

Relative Luminous Intensity vs. Junction temperature Tj(°C)
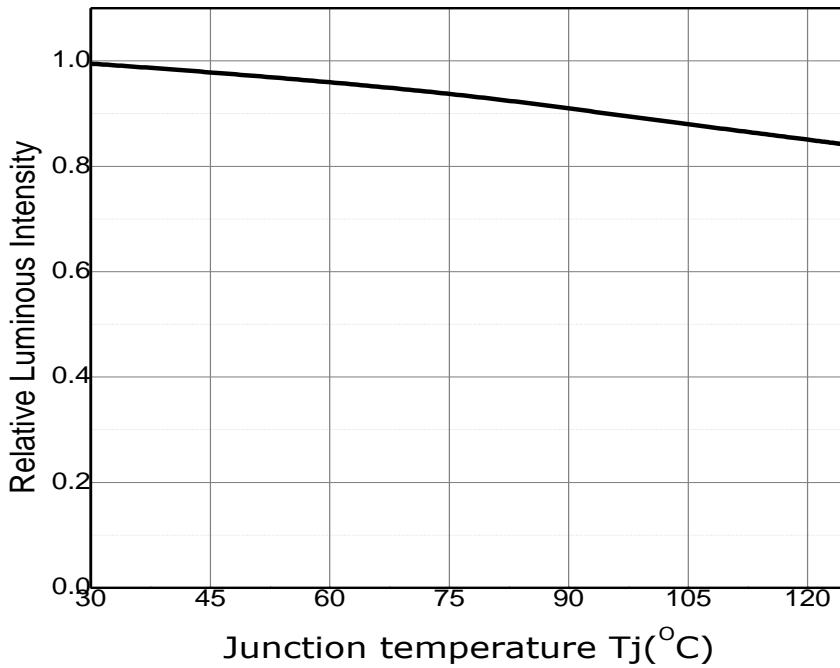
Fig 7. Junction Temperature vs. Relative Forward Voltage

I_F = 100mA

Relative Forward Voltage vs. Junction temperature Tj(°C)
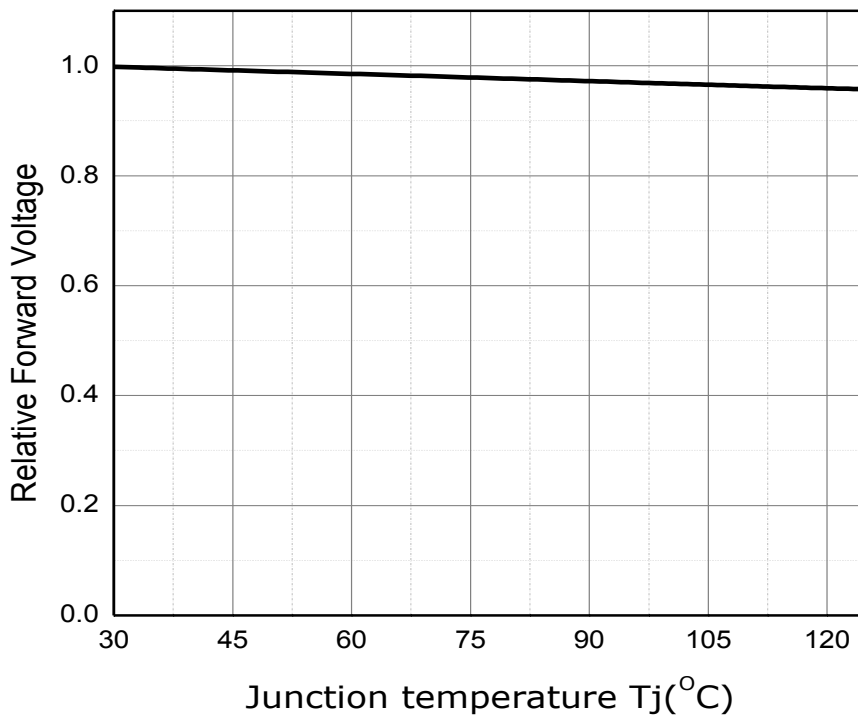
Characteristics Graph

Fig 8. Chromaticity Coordinate vs. Junction Temperature

I_F = 100mA
(4200~7000K)
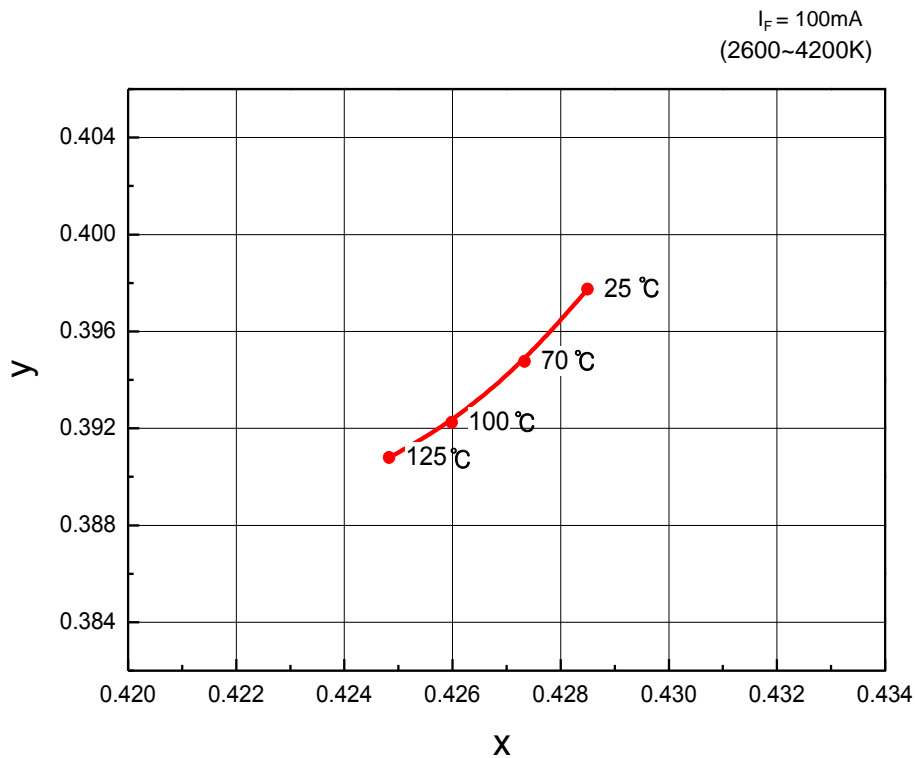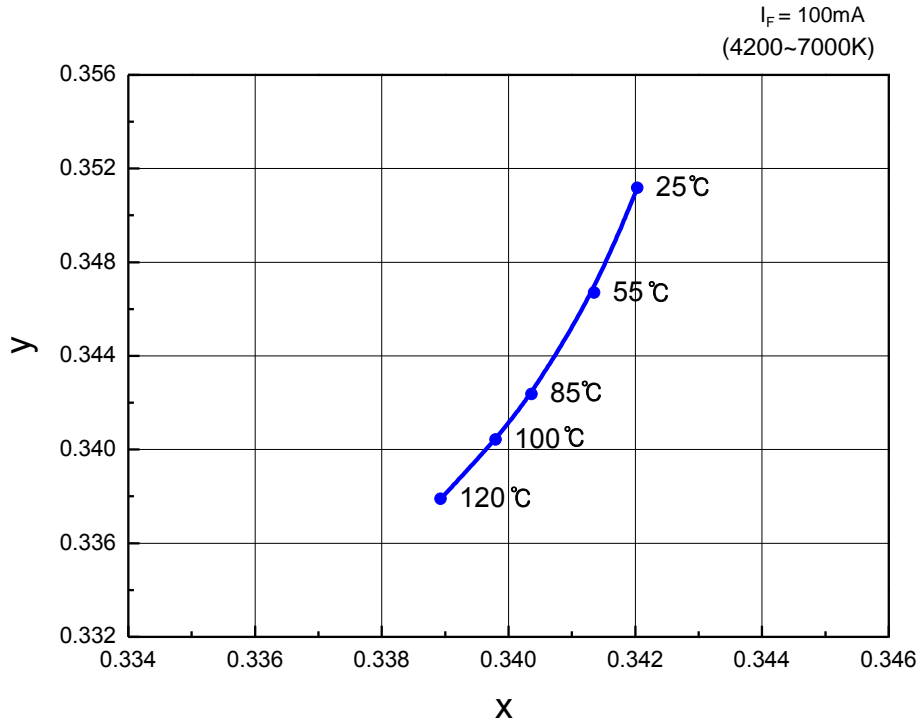
I_F = 100mA
(2600~4200K)

Characteristics Graph

Fig 9. Maximum Forward Current vs. Ambient Temperature

Rth $_{j-a}$: 60 ℃/W
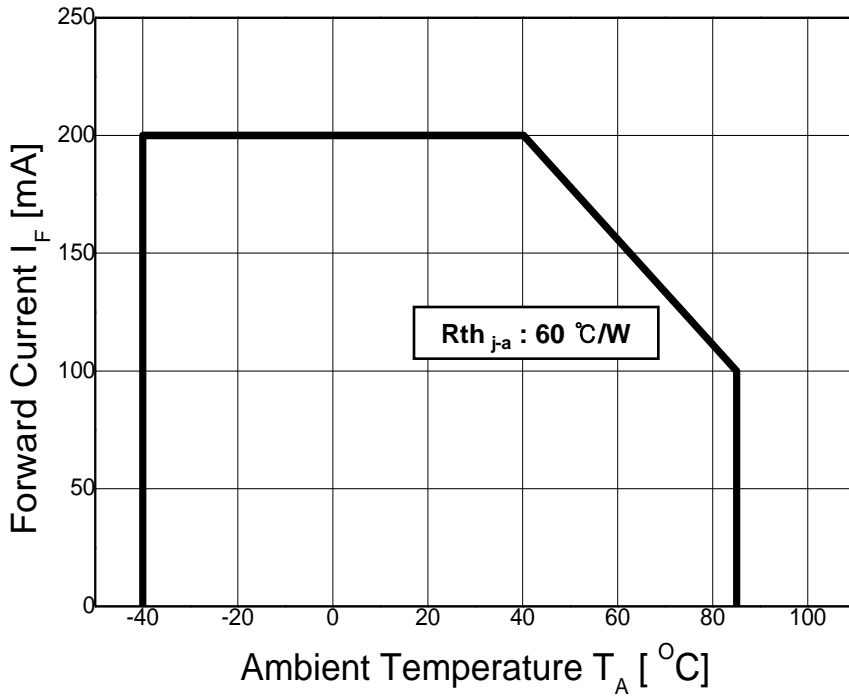
Color Bin Structure

Table 4. Bin Code description

Part Number	Luminous Intensity (cd) @ I_F = 100mA			Color Chromaticity Coordinate @ I_F = 100mA	Typical Forward Voltage (V_F) @ I_F = 100mA		
	Bin Code	Min.	Max.		Bin Code	Min.	Max.
STW9C2SA	J17	17	19.5	Refer to page.14	Z56	5.6	5.8
	J19	19.5	21.5		Z58	5.8	6.0
	K21	21.5 (21.0) [1]	24		Z60	6.0	6.2
	K24	24	26		Z62	6.2	6.4
					Z64	6.4	6.6

Table 5. Intensity rank distribution 　　　　　　　　　　　　　 Available ranks

CCT	CIE	IV Rank			
6000- 7000K	A	J17	J19	K21	K24
5300- 6000K	B	J17	J19	K21	K24
4700 ~ 5300K	C	J17	J19	K21	K24
4200 ~ 4700K	D	J17	J19	K21	K24
3700 ~ 4200K	E	J17	J19	K21	K24
3200 ~ 3700K	F	J17	J19	K21	K24
2900 ~ 3200K	G	J17	J19	K21	K24
2600 - 2900K	H	J17	J19	K21	K24

*Notes :
 All measurements were made under the standardized environment of SSC.
 In order to ensure availability, single color rank will not be orderable.

(1)Exceptively, at CCT 3000K (CIE G) and 2700K (CIE H) of STW9C2SA, IV rank K21's Minimum Luminous Intensity(cd) is 21cd.

Color Bin Structure

CIE Chromaticity Diagram T_a = 25℃, I_F = 100mA

MACADAM 3STEP Rank
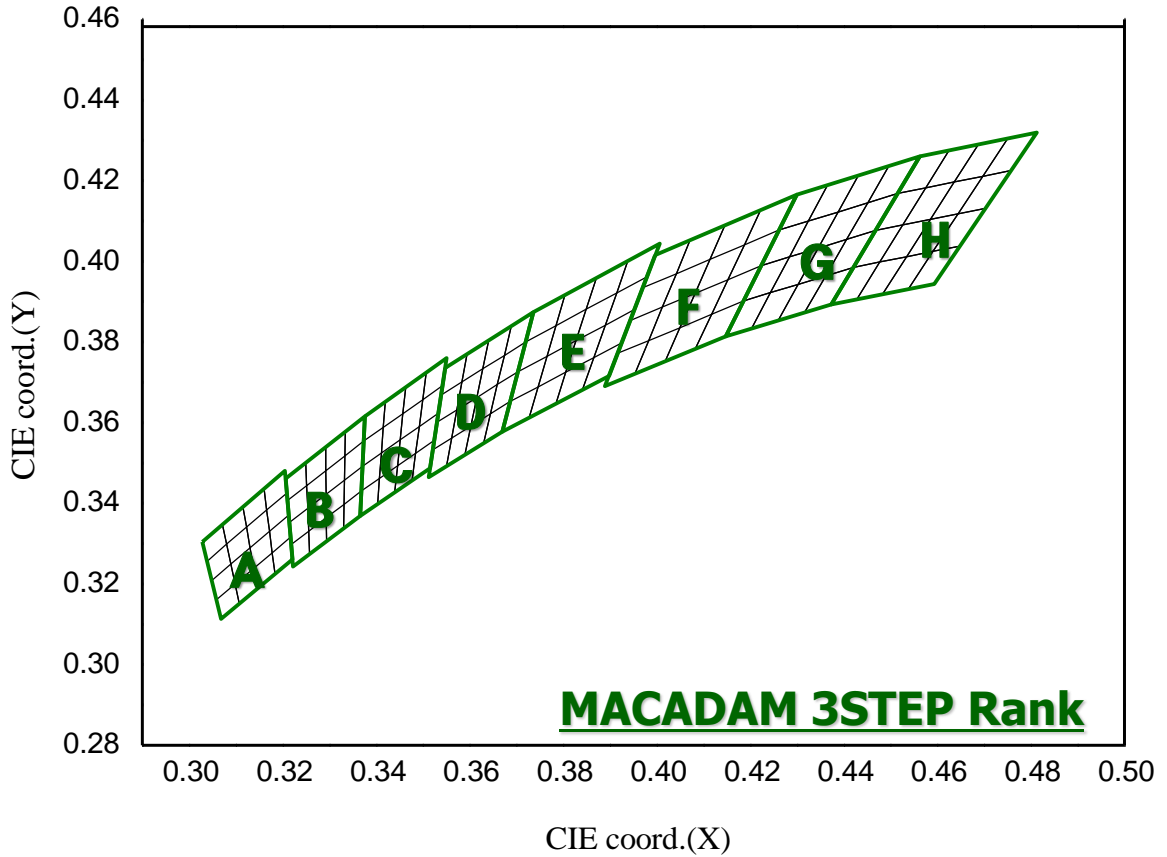
- Energy Star binning applied to all 2600~7000K.
- Measurement Uncertainty of the Color Coordinates : ± 0.007

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Color Bin Structure

<I$_F$ = 100mA, T$_a$ = 25℃>

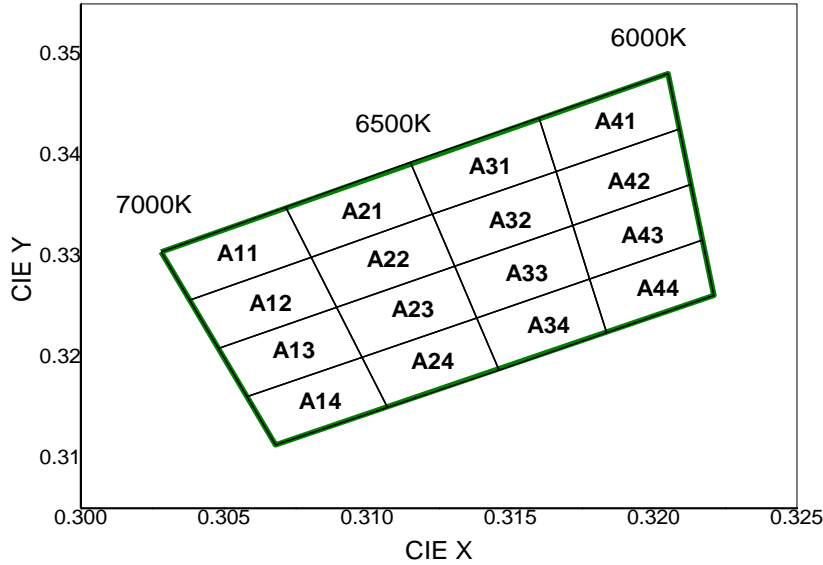| A11		A21		A31		A41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3028	0.3304	0.3072	0.3349	0.3115	0.3393	0.3160	0.3437
0.3038	0.3256	0.3080	0.3299	0.3123	0.3342	0.3166	0.3384
0.3080	0.3299	0.3123	0.3342	0.3166	0.3384	0.3209	0.3426
0.3072	0.3349	0.3115	0.3393	0.3160	0.3437	0.3205	0.3481
A12		**A22**		**A32**		**A42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3038	0.3256	0.3080	0.3299	0.3123	0.3342	0.3166	0.3384
0.3048	0.3209	0.3089	0.3249	0.3131	0.3290	0.3172	0.3331
0.3089	0.3249	0.3131	0.3290	0.3172	0.3331	0.3213	0.3371
0.3080	0.3299	0.3123	0.3342	0.3166	0.3384	0.3209	0.3426
A13		**A23**		**A33**		**A43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3048	0.3209	0.3089	0.3249	0.3131	0.3290	0.3172	0.3331
0.3058	0.3161	0.3098	0.3200	0.3138	0.3239	0.3178	0.3277
0.3098	0.3200	0.3138	0.3239	0.3178	0.3277	0.3217	0.3316
0.3089	0.3249	0.3131	0.3290	0.3172	0.3331	0.3213	0.3371
A14		**A24**		**A34**		**A44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3058	0.3161	0.3098	0.3200	0.3138	0.3239	0.3178	0.3277
0.3068	0.3113	0.3107	0.3150	0.3146	0.3187	0.3184	0.3224
0.3107	0.3150	0.3146	0.3187	0.3184	0.3224	0.3221	0.3261
0.3098	0.3200	0.3138	0.3239	0.3178	0.3277	0.3217	0.3316

Color Bin Structure

$<I_F = 100mA, T_a = 25℃>$
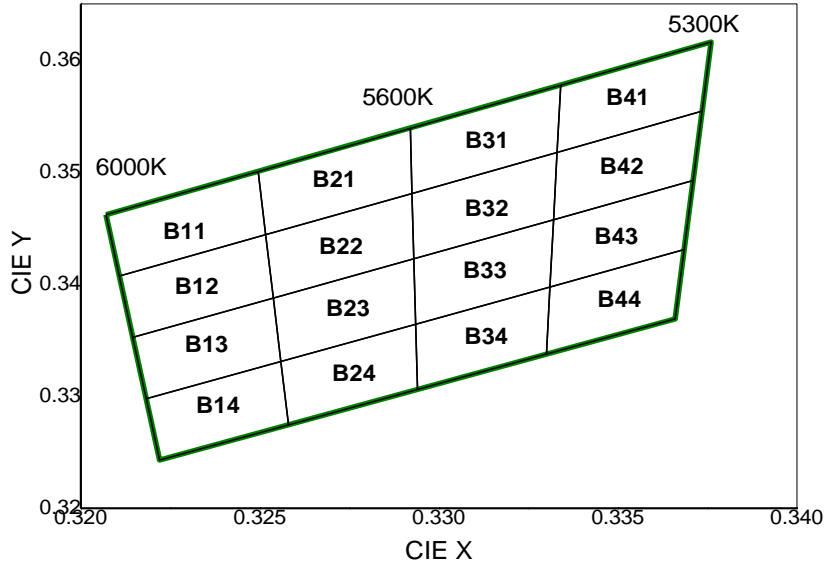
B11		B21		B31		B41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3207	0.3462	0.3250	0.3501	0.3292	0.3539	0.3334	0.3578
0.3211	0.3407	0.3252	0.3444	0.3293	0.3481	0.3333	0.3518
0.3252	0.3444	0.3293	0.3481	0.3333	0.3518	0.3374	0.3554
0.3250	0.3501	0.3292	0.3539	0.3334	0.3578	0.3376	0.3616
B12		**B22**		**B32**		**B42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3211	0.3407	0.3252	0.3444	0.3293	0.3481	0.3333	0.3518
0.3215	0.3353	0.3254	0.3388	0.3293	0.3423	0.3332	0.3458
0.3254	0.3388	0.3293	0.3423	0.3332	0.3458	0.3371	0.3493
0.3252	0.3444	0.3293	0.3481	0.3333	0.3518	0.3374	0.3554
B13		**B23**		**B33**		**B43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3215	0.3353	0.3254	0.3388	0.3293	0.3423	0.3332	0.3458
0.3218	0.3298	0.3256	0.3331	0.3294	0.3364	0.3331	0.3398
0.3256	0.3331	0.3294	0.3364	0.3331	0.3398	0.3369	0.3431
0.3254	0.3388	0.3293	0.3423	0.3332	0.3458	0.3371	0.3493
B14		**B24**		**B34**		**B44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3218	0.3298	0.3256	0.3331	0.3294	0.3364	0.3331	0.3398
0.3222	0.3243	0.3258	0.3275	0.3294	0.3306	0.3330	0.3338
0.3258	0.3275	0.3294	0.3306	0.3330	0.3338	0.3366	0.3369
0.3256	0.3331	0.3294	0.3364	0.3331	0.3398	0.3369	0.3431

Color Bin Structure

<I$_F$ = 100mA, T$_a$ = 25℃>
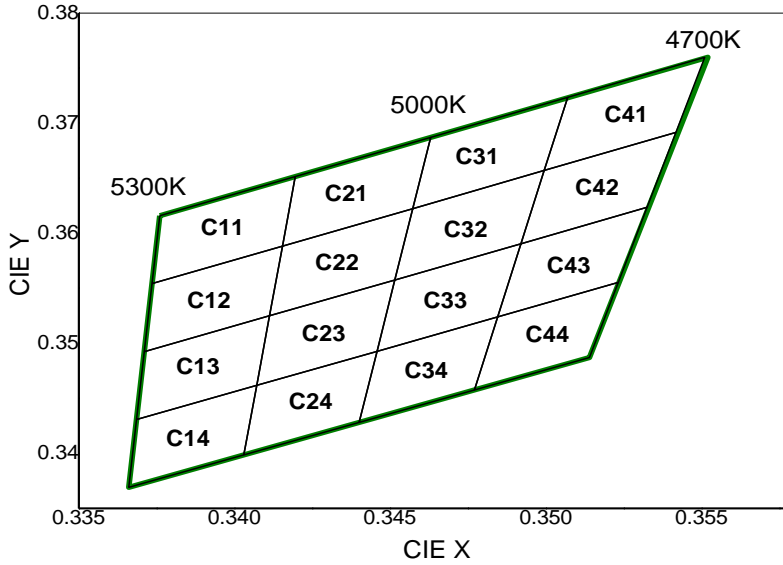
C11		C21		C31		C41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3376	0.3616	0.3420	0.3652	0.3463	0.3687	0.3507	0.3724
0.3374	0.3554	0.3415	0.3588	0.3457	0.3622	0.3500	0.3657
0.3415	0.3588	0.3457	0.3622	0.3500	0.3657	0.3542	0.3692
0.3420	0.3652	0.3463	0.3687	0.3507	0.3724	0.3551	0.3760
C12		**C22**		**C32**		**C42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3374	0.3554	0.3415	0.3588	0.3457	0.3622	0.3500	0.3657
0.3371	0.3493	0.3411	0.3525	0.3452	0.3558	0.3492	0.3591
0.3411	0.3525	0.3452	0.3558	0.3492	0.3591	0.3533	0.3624
0.3415	0.3588	0.3457	0.3622	0.3500	0.3657	0.3542	0.3692
C13		**C23**		**C33**		**C43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3371	0.3493	0.3411	0.3525	0.3452	0.3558	0.3492	0.3591
0.3369	0.3431	0.3407	0.3462	0.3446	0.3493	0.3485	0.3524
0.3407	0.3462	0.3446	0.3493	0.3485	0.3524	0.3523	0.3555
0.3411	0.3525	0.3452	0.3558	0.3492	0.3591	0.3533	0.3624
C14		**C24**		**C34**		**C44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3369	0.3431	0.3407	0.3462	0.3446	0.3493	0.3485	0.3524
0.3366	0.3369	0.3403	0.3399	0.3440	0.3428	0.3477	0.3458
0.3403	0.3399	0.3440	0.3428	0.3477	0.3458	0.3514	0.3487
0.3407	0.3462	0.3446	0.3493	0.3485	0.3524	0.3523	0.3555

Color Bin Structure

<IF = 100mA, Ta = 25℃>
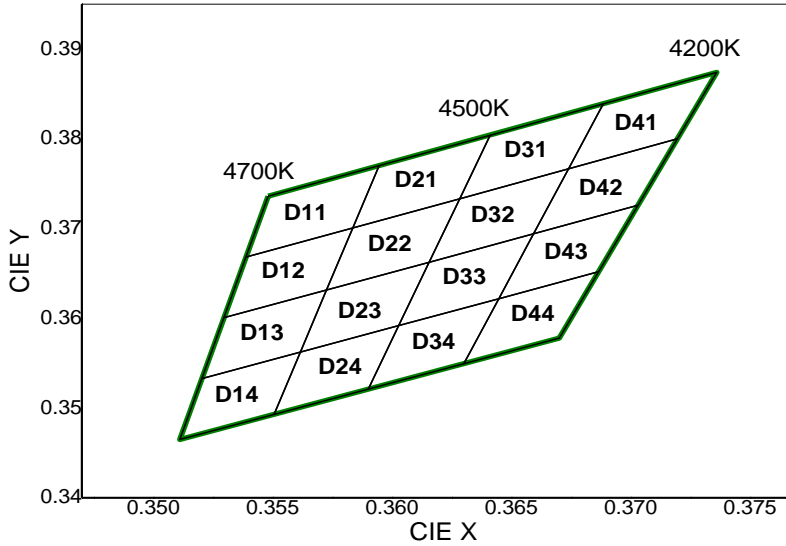
D11		D21		D31		D41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3548	0.3736	0.3595	0.3770	0.3641	0.3804	0.3689	0.3839
0.3539	0.3668	0.3584	0.3701	0.3628	0.3733	0.3674	0.3767
0.3584	0.3701	0.3628	0.3733	0.3674	0.3767	0.3720	0.3800
0.3595	0.3770	0.3641	0.3804	0.3689	0.3839	0.3736	0.3874

D12		D22		D32		D42	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3539	0.3668	0.3584	0.3701	0.3628	0.3733	0.3674	0.3767
0.3530	0.3601	0.3573	0.3632	0.3616	0.3663	0.3659	0.3694
0.3573	0.3632	0.3616	0.3663	0.3659	0.3694	0.3703	0.3726
0.3584	0.3701	0.3628	0.3733	0.3674	0.3767	0.3720	0.3800

D13		D23		D33		D43	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3530	0.3601	0.3573	0.3632	0.3616	0.3663	0.3659	0.3694
0.3520	0.3533	0.3562	0.3562	0.3603	0.3592	0.3645	0.3622
0.3562	0.3562	0.3603	0.3592	0.3645	0.3622	0.3687	0.3652
0.3573	0.3632	0.3616	0.3663	0.3659	0.3694	0.3703	0.3726

D14		D24		D34		D44	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3520	0.3533	0.3562	0.3562	0.3603	0.3592	0.3645	0.3622
0.3511	0.3465	0.3551	0.3493	0.3590	0.3521	0.3630	0.3550
0.3551	0.3493	0.3590	0.3521	0.3630	0.3550	0.3670	0.3578
0.3562	0.3562	0.3603	0.3592	0.3645	0.3622	0.3687	0.3652

Color Bin Structure

<$I_F = 100mA, T_a = 25℃>
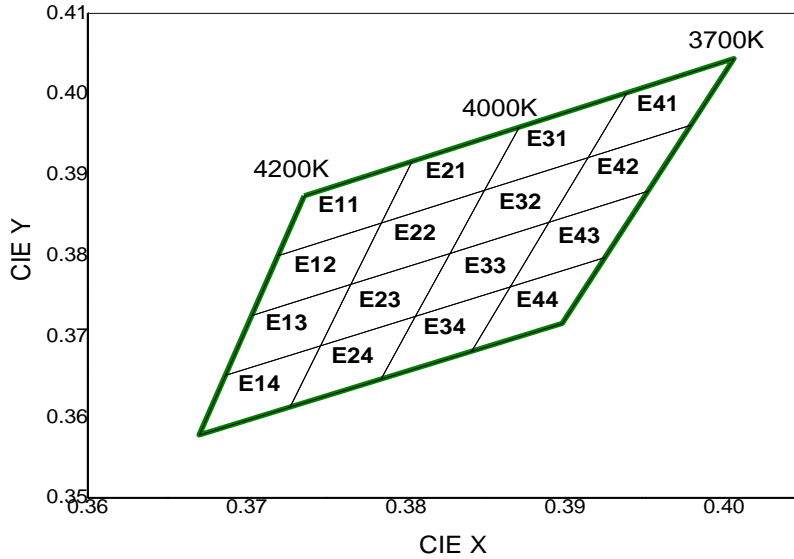
E11		E21		E31		E41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3736	0.3874	0.3804	0.3917	0.3871	0.3959	0.3939	0.4002
0.3720	0.3800	0.3784	0.3841	0.3849	0.3881	0.3914	0.3922
0.3784	0.3841	0.3849	0.3881	0.3914	0.3922	0.3979	0.3962
0.3804	0.3917	0.3871	0.3959	0.3939	0.4002	0.4006	0.4044
E12		**E22**		**E32**		**E42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3720	0.3800	0.3784	0.3841	0.3849	0.3881	0.3914	0.3922
0.3703	0.3726	0.3765	0.3765	0.3828	0.3803	0.3890	0.3842
0.3765	0.3765	0.3828	0.3803	0.3890	0.3842	0.3952	0.3880
0.3784	0.3841	0.3849	0.3881	0.3914	0.3922	0.3979	0.3962
E13		**E23**		**E33**		**E43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3703	0.3726	0.3765	0.3765	0.3828	0.3803	0.3890	0.3842
0.3687	0.3652	0.3746	0.3689	0.3806	0.3725	0.3865	0.3762
0.3746	0.3689	0.3806	0.3725	0.3865	0.3762	0.3925	0.3798
0.3765	0.3765	0.3828	0.3803	0.3890	0.3842	0.3952	0.3880
E14		**E24**		**E34**		**E44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3687	0.3652	0.3746	0.3689	0.3806	0.3725	0.3865	0.3762
0.3670	0.3578	0.3727	0.3613	0.3784	0.3647	0.3841	0.3682
0.3727	0.3613	0.3784	0.3647	0.3841	0.3682	0.3898	0.3716
0.3746	0.3689	0.3806	0.3725	0.3865	0.3762	0.3925	0.3798

Color Bin Structure

<$I_F = 100mA, T_a = 25℃>$
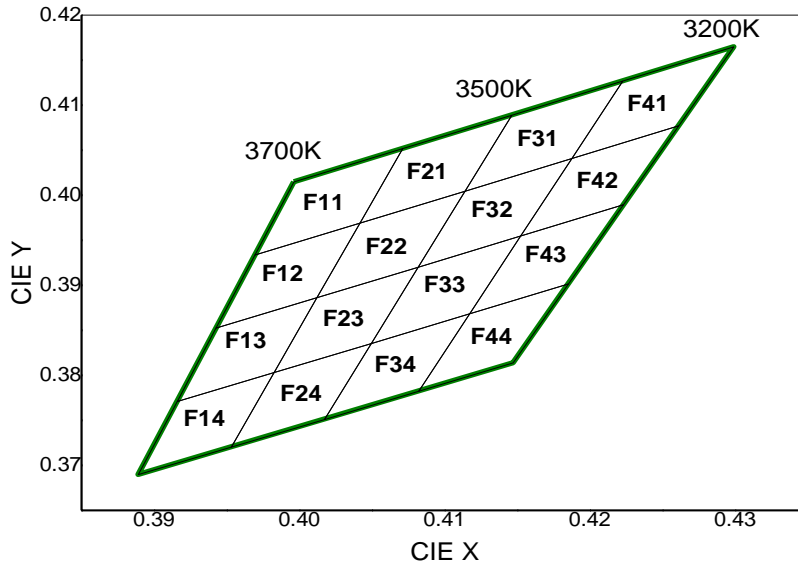
F11		F21		F31		F41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3996	0.4015	0.4071	0.4052	0.4146	0.4089	0.4223	0.4127
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077
0.4071	0.4052	0.4146	0.4089	0.4223	0.4127	0.4299	0.4165

F12		F22		F32		F42	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.3943	0.3853	0.4012	0.3886	0.4082	0.3920	0.4152	0.3955
0.4012	0.3886	0.4082	0.3920	0.4152	0.3955	0.4223	0.3990
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077

F13		F23		F33		F43	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3943	0.3853	0.4012	0.3886	0.4082	0.3920	0.4152	0.3955
0.3916	0.3771	0.3983	0.3803	0.4049	0.3836	0.4117	0.3869
0.3983	0.3803	0.4049	0.3836	0.4117	0.3869	0.4185	0.3902
0.4012	0.3886	0.4082	0.3920	0.4152	0.3955	0.4223	0.3990

F14		F24		F34		F44	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3916	0.3771	0.3983	0.3803	0.4049	0.3836	0.4117	0.3869
0.3889	0.3690	0.3953	0.3721	0.4017	0.3751	0.4082	0.3783
0.3953	0.3721	0.4017	0.3751	0.4082	0.3783	0.4147	0.3814
0.3983	0.3803	0.4049	0.3836	0.4117	0.3869	0.4185	0.3902

SEOUL SEMICONDUCTOR

Color Bin Structure

$<I_F = 100mA, T_a = 25℃>$
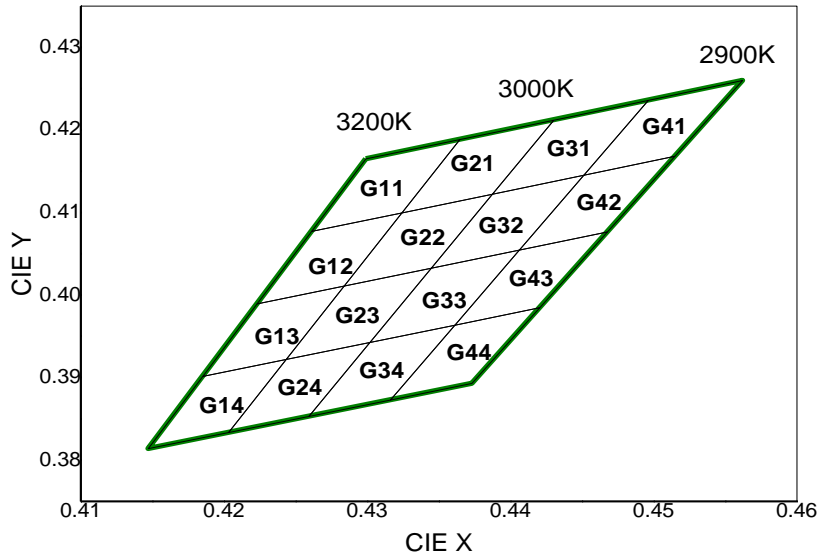
G11		G21		G31		G41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4299	0.4165	0.4364	0.4188	0.4430	0.4212	0.4496	0.4236
0.4261	0.4077	0.4324	0.4099	0.4387	0.4122	0.4451	0.4145
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4514	0.4168
0.4365	0.4189	0.4430	0.4212	0.4496	0.4236	0.4562	0.4260
G12		**G22**		**G32**		**G42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4261	0.4077	0.4324	0.4100	0.4387	0.4122	0.4451	0.4145
0.4223	0.3990	0.4284	0.4011	0.4345	0.4033	0.4406	0.4055
0.4284	0.4011	0.4345	0.4033	0.4406	0.4055	0.4468	0.4077
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4515	0.4168
G13		**G23**		**G33**		**G43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4223	0.3990	0.4284	0.4011	0.4345	0.4033	0.4406	0.4055
0.4185	0.3902	0.4243	0.3922	0.4302	0.3943	0.4361	0.3964
0.4243	0.3922	0.4302	0.3943	0.4361	0.3964	0.4420	0.3985
0.4284	0.4011	0.4345	0.4033	0.4406	0.4055	0.4468	0.4077
G14		**G24**		**G34**		**G44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4243	0.3922	0.4302	0.3943	0.4302	0.3943	0.4361	0.3964
0.4203	0.3834	0.4259	0.3853	0.4259	0.3853	0.4316	0.3873
0.4147	0.3814	0.4203	0.3834	0.4316	0.3873	0.4373	0.3893
0.4185	0.3902	0.4243	0.3922	0.4361	0.3964	0.4420	0.3985

Color Bin Structure

$<I_F = 100mA, T_a = 25℃>$
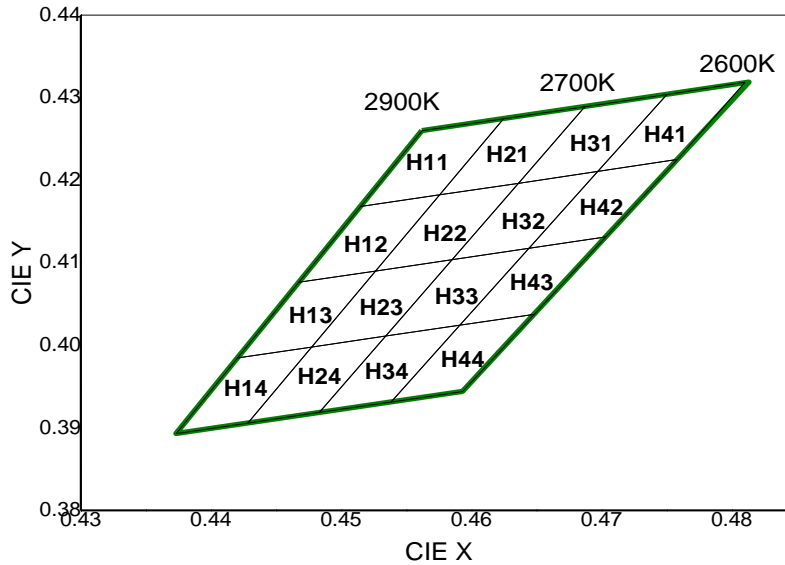
H11		H21		H31		H41	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4562	0.4260	0.4625	0.4275	0.4687	0.4289	0.4750	0.4304
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
0.4625	0.4275	0.4687	0.4289	0.4750	0.4304	0.4810	0.4319
H12		**H22**		**H32**		**H42**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4526	0.4090	0.4585	0.4104	0.4644	0.4118	0.4703	0.4132
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
H13		**H23**		**H33**		**H43**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4420	0.3985	0.4477	0.3998	0.4534	0.4012	0.4591	0.4025
0.4477	0.3998	0.4534	0.4012	0.4591	0.4025	0.4648	0.4038
0.4526	0.4090	0.4585	0.4104	0.4644	0.4118	0.4703	0.4132
H14		**H24**		**H34**		**H44**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4420	0.3985	0.4477	0.3998	0.4534	0.4012	0.4591	0.4025
0.4373	0.3893	0.4428	0.3906	0.4483	0.3919	0.4538	0.3932
0.4428	0.3906	0.4483	0.3919	0.4538	0.3932	0.4593	0.3944
0.4477	0.3998	0.4534	0.4012	0.4591	0.4025	0.4648	0.4038

Mechanical Dimensions

Top View

3.00

3.00

**Cathode
Mark (-)**

Bottom View

2.270

Cathode

0.51 0.56   1.43

Side View

0.65

Circuit

Cathode   Anode

1   2

Zener Diode
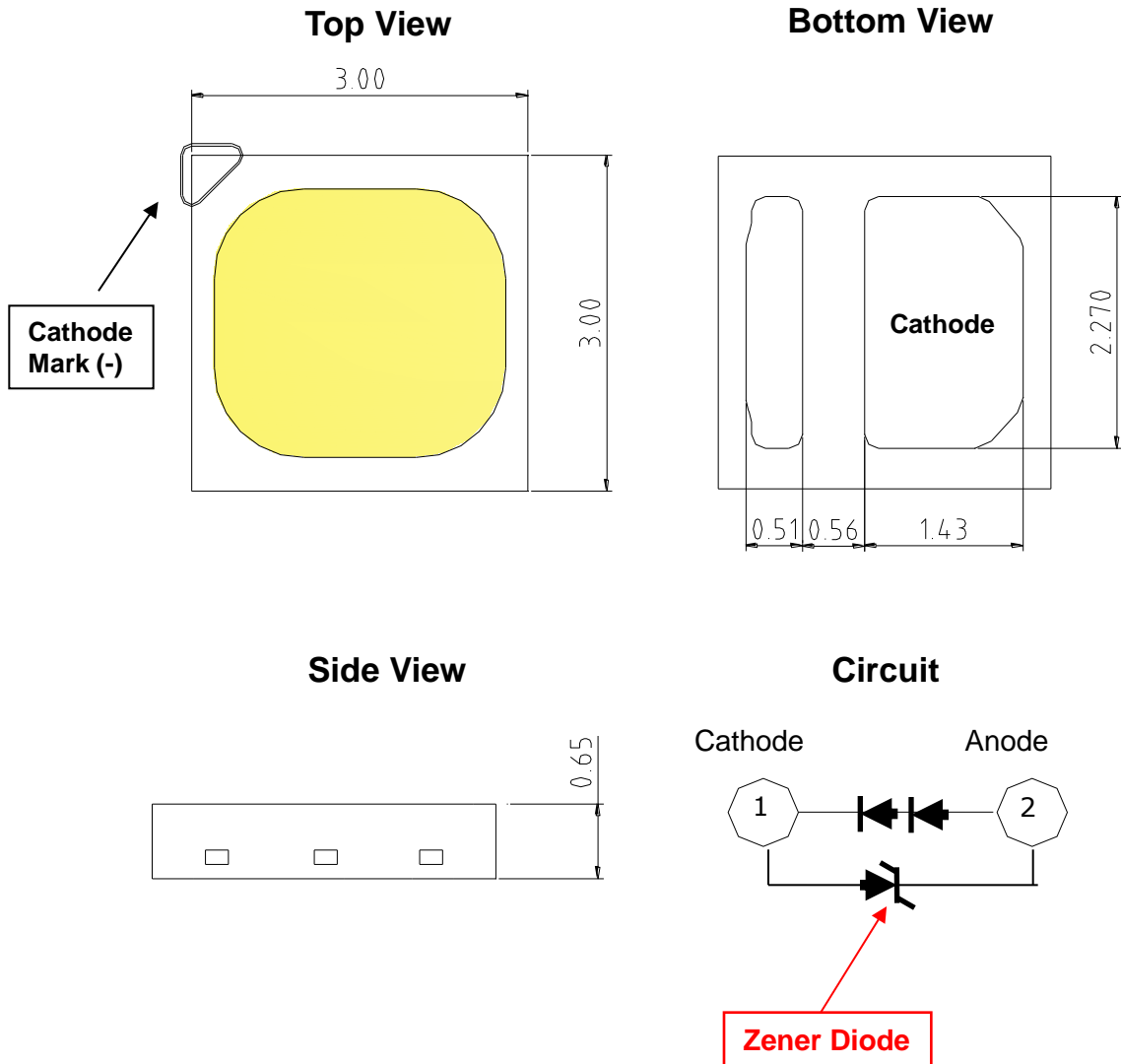
(1) All dimensions are in millimeters.

(2) Scale : none

(3) Undefined tolerance is ±0.2mm

Mechanical Dimensions
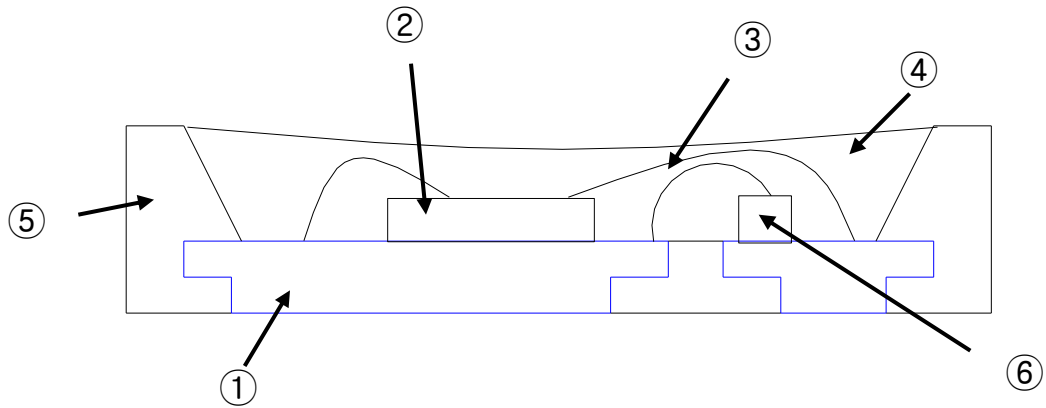
Parts No.	Name	Description	Materials
①	LEAD FRAME	Metal	Copper Alloy (Silver Plated)
②	Light souce	Blue LED	GaN on Sapphire
③	Circuit wiring	Wire Bonding	Gold
④	Encapsulation	Encapsulation	Silicone+Phosphor
⑤	Body	-	Heat-resistant Polymer
⑥	ESD Protection Device	Zener Diode	Silicon(Si)

Recommended Solder Pad
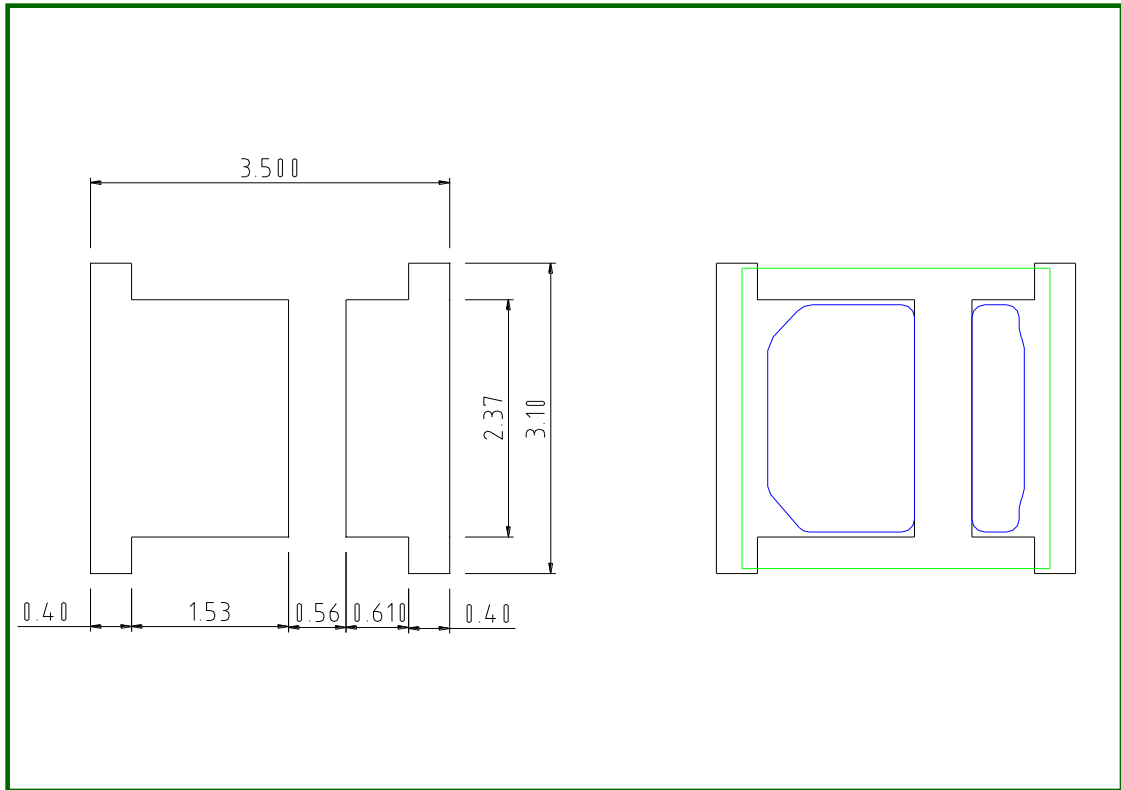
Notes :

(1) All dimensions are in millimeters.

(2) Scale : none

(3) This drawing without tolerances are for reference only

(4) Undefined tolerance is $\pm$0.1mm

Reflow Soldering Characteristics

IPC/JEDEC J-STD-020
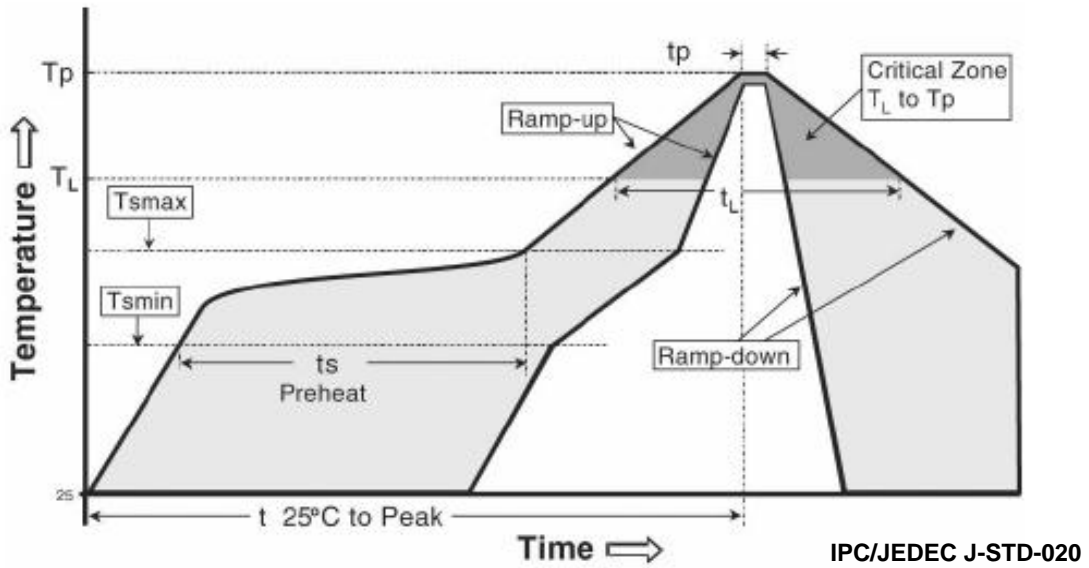
Table 8.

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (Tp)	215℃	260℃
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

(1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
(2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
(3) Die slug is to be soldered.
(4) When soldering, do not put stress on the LEDs during heating.
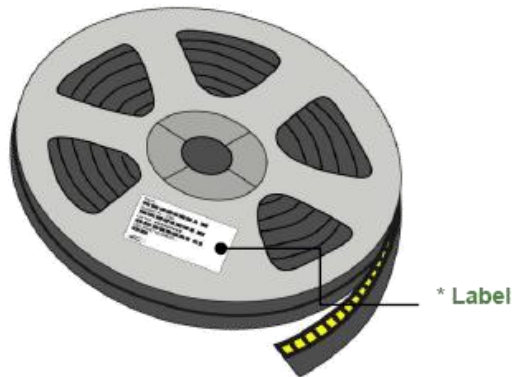(5) After soldering, do not warp the circuit board.

Reel Packaging
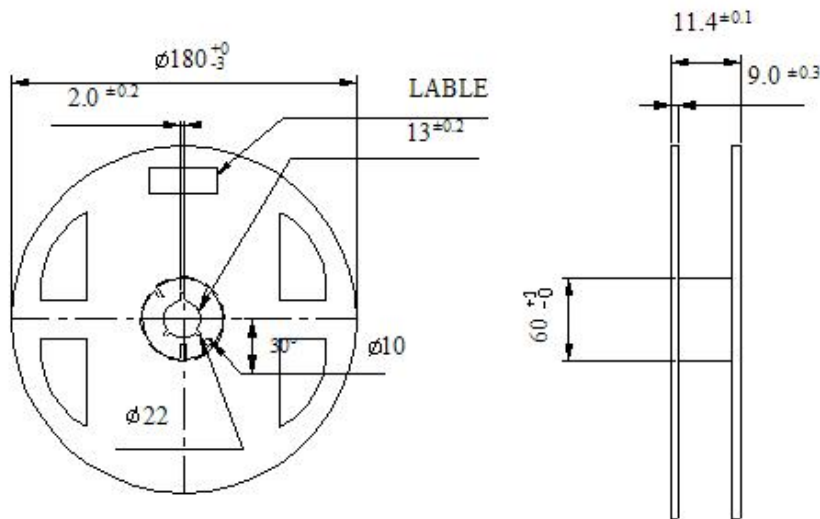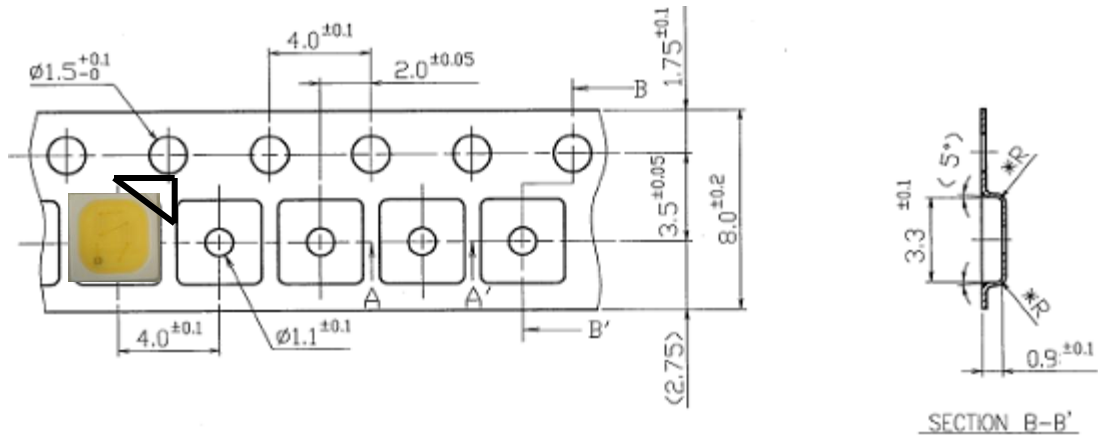
(Tolerance: ±0.2, Unit: mm)

(1) Quantity : Max 4,500pcs/Reel
(2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ±0.2mm
(3) Adhesion Strength of Cover Tape
   Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape
   at the angle of 10˚ to the carrier tape.
(4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.
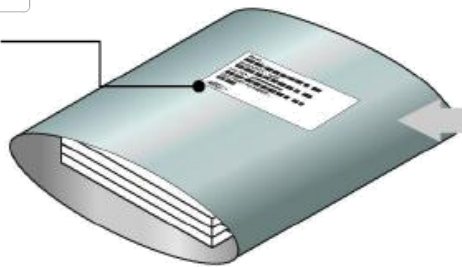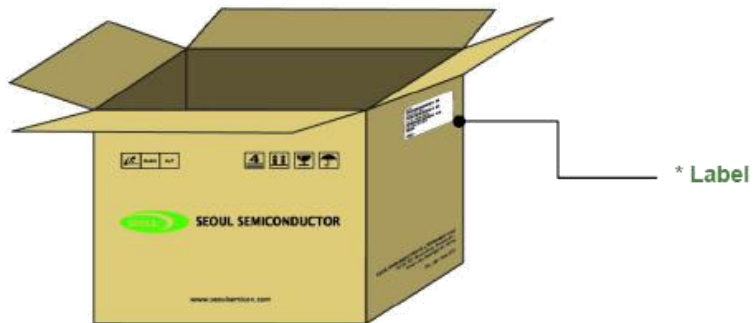
Reel Packaging

Reel

* Label

Aluminum Bag

* Label

Humidity Indicator

Desiccant

Outer Box

SEOUL SEMICONDUCTOR

* Label

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Product Nomenclature

Table 6. Part Numbering System : $X_1X_2X_3\ X_4X_5\ X_6X_7$

Part Number Code	Description	Part Number	Value
X_1	Company	S	
X_2	Top View LED series	T	
X_3	Color Specification	W9	CRI 90
X_4	Package series	C	3030 series
X_5X_6	Characteristic code	2S	
X_7	Revision	A	

Table 7. Lot Numbering System :$Y_1Y_2Y_3Y_4Y_5Y_6Y_7Y_8Y_9Y_{10}$–$Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$

Lot Number Code	Description	Lot Number	Value
Y_1Y_2	Year		
Y_3	Month		
Y_4Y_5	Day		
Y_6	Top View LED series		
$Y_7Y_8Y_9Y_{10}$	Mass order		
$Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$	Internal Number		

Handling 3030 Series LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.
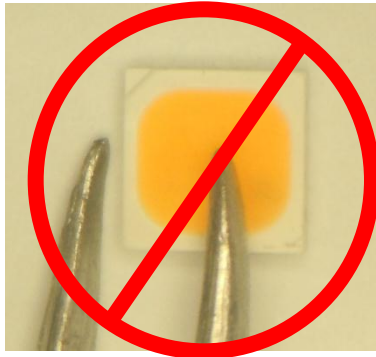
(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.
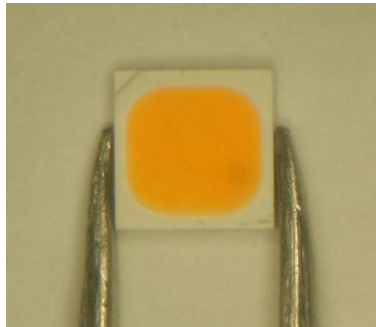
(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

 As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.
 Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this.
 product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant.

The recommended storage temperature range is 5℃ to 30℃ and a maximum humidity of

RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMT techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

a. Recommend conditions after opening the package

- Sealing

- Temperature : 5 ~ 40℃ Humidity : less than RH30%

b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant

changes, components should be dried for 10-12hr at 60±5℃

(3) Do not apply mechanical force or excess vibration during the cooling process to normal

temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication.

These products are dangerous if they are burned or shredded in the process of disposal.

It is also dangerous to drink the liquid or inhale the gas generated by such products when

chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring

the package temperature.

(10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or

more after being shipped from SSC, a sealed container with a nitrogen atmosphere should

be used for storage.

Precaution for Use

(11) The appearance and specifications of the product may be modified for improvement without notice.

(12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

(13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(14) Attaching LEDs, do not use adhesives that outgas organic vapor.

(15) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.
If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(16) Similar to most Solid state devices;
LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).
Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event.
One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:
- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:
- Humidity control (ESD gets worse in a dry environment)

Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated
  the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
  (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device

Company Information

Published by

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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